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# 2SA1962/FJA4213 **PNP Epitaxial Silicon Transistor**

## **Applications**

- High-Fidelity Audio Output Amplifier
- General Purpose Power Amplifier

### Features

- High Current Capability:  $I_C = -17A$
- High Power Dissipation : 130watts
- High Frequency : 30MHz. ٠
- High Voltage : V<sub>CEO</sub>= -250V
- Wide S.O.A for reliable operation.
- Excellent Gain Linearity for low THD.
- Complement to 2SC5242/FJA4313.
- Thermal and electrical Spice models are available.
- · Same transistor is also available in:
  - -- TO264 package, 2SA1943/FJL4215 : 150 watts
  - -- TO220 package, FJP1943 : 80 watts
  - -- TO220F package, FJPF1943 : 50 watts

### Absolute Maximum Ratings\* T<sub>a</sub> = 25°C unless otherwise noted

Symbol	ymbol Parameter		Units	
BV <sub>CBO</sub>	Collector-Base Voltage	-250	V	
BV <sub>CEO</sub>	Collector-Emitter Voltage	-250	V	
BV <sub>EBO</sub> Emitter-Base Voltage		-5	V	
I <sub>C</sub>	Collector Current	-17	А	
I <sub>B</sub> Base Current		-1.5	А	
P <sub>D</sub>	Total Device Dissipation(T <sub>C</sub> =25°C) Derate above 25°C	130 1.04	W W/°C	
T <sub>J</sub> , T <sub>STG</sub>	Junction and Storage Temperature	- 50 ~ +150	°C	

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### Thermal Characteristics\* Ta=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	0.96	°C/W

\* Device mounted on minimum pad size

## h<sub>FE</sub> Classification

Classification	R	0
h <sub>FE1</sub>	55 ~ 110	80 ~ 160

TO-3P 1.Base 2.Collector 3.Emitter

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January 2009

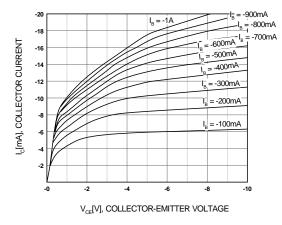
Electrical Characteristics* T <sub>a</sub> =25°C unless otherwise noted						
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =-5mA, I <sub>E</sub> =0	-250			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C$ =-10mA, $R_{BE}$ = $\infty$	-250			V
$BV_EBO$	Emitter-Base Breakdown Voltage	I <sub>E</sub> =-5mA, I <sub>C</sub> =0	-5			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =-230V, I <sub>E</sub> =0			-5.0	μA
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> =-5V, I <sub>C</sub> =0			-5.0	μA
h <sub>FE1</sub>	DC Current Gain	V <sub>CE</sub> =-5V, I <sub>C</sub> =-1A	55		160	
h <sub>FE2</sub>	DC Current Gain	V <sub>CE</sub> =-5V, I <sub>C</sub> =-7A	35	60		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =-8A, I <sub>B</sub> =-0.8A		-0.4	-3.0	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	V <sub>CE</sub> =-5V, I <sub>C</sub> =-7A		-1.0	-1.5	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =-5V, I <sub>C</sub> =-1A		30		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =-10V, f=1MHz		360		pF

\* Pulse Test: Pulse Width=20µs, Duty Cycle≤2%

# **Ordering Information**

Part Number	Marking	Package	Packing Method	Remarks
2SA1962RTU	A1962R	TO-3P	TUBE	hFE1 R grade
2SA1962OTU	A1962O	TO-3P	TUBE	hFE1 O grade
FJA4213RTU	J4213R	TO-3P	TUBE	hFE1 R grade
FJA4213OTU	J4213O	TO-3P	TUBE	hFE1 O grade

# **Typical Characteristics**





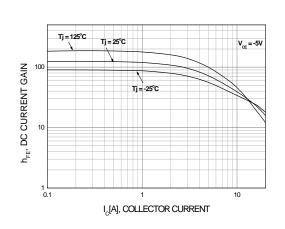
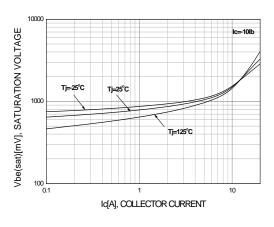


Figure 3. DC current Gain (O Grade)





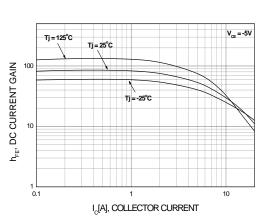


Figure 2. DC current Gain ( R Grade )

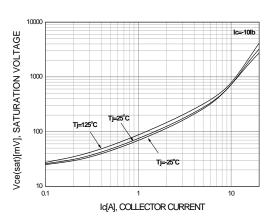
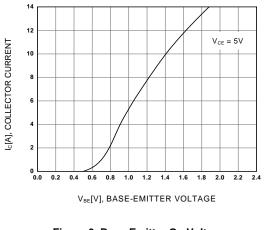


Figure 4. Collector-Emitter Saturation Voltage





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# **Typical Characteristics**

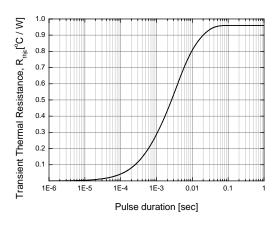


Figure 7. Thermal Resistance

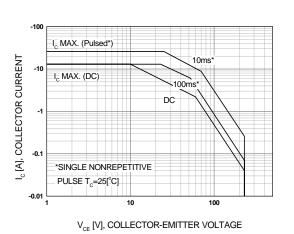


Figure 8. Safe Operating Area

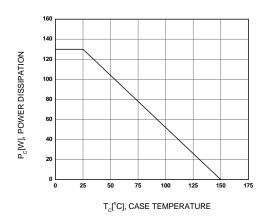
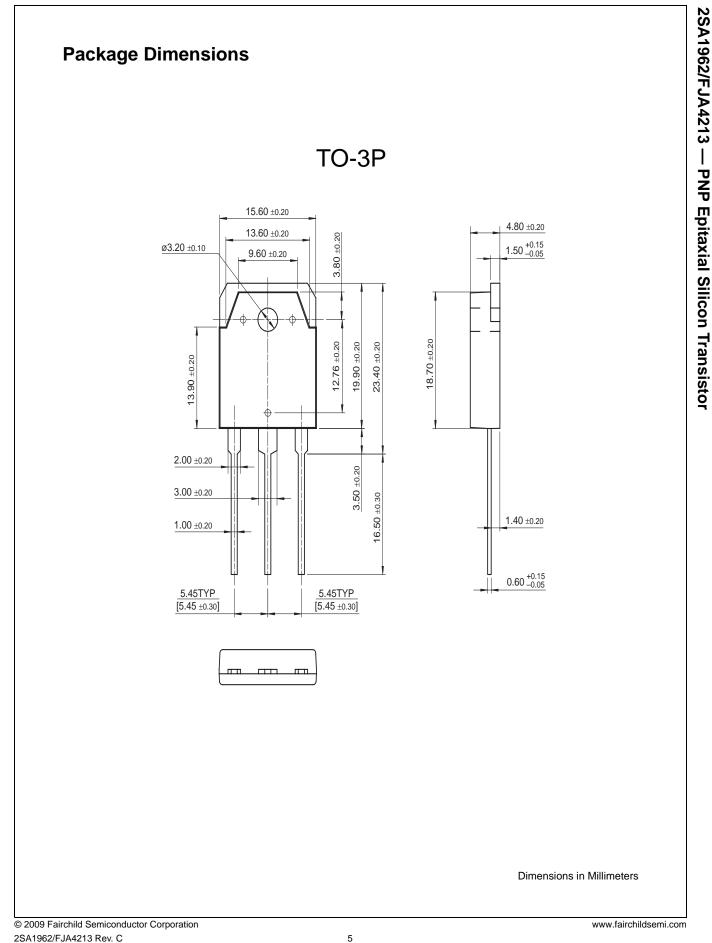
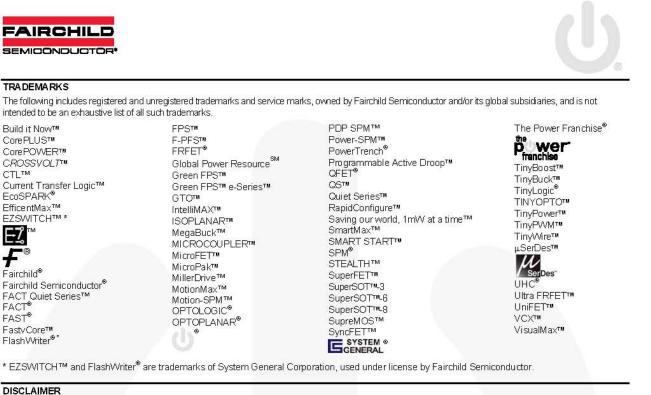


Figure 9. Power Derating

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No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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